

FMMT614Q

#### 100V NPN DARLINGTON MEDIUM POWER TRANSISTOR IN SOT23

#### **Description**

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

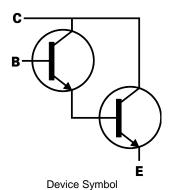
#### **Features**

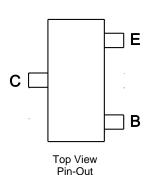
- BV<sub>CEO</sub> > 100V
- I<sub>C</sub> = 0.5A High Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- 500mW Power Dissipation
- Darlington transistor with high  $h_{FE}$  up to 5k at  $I_C = 0.5A$
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

- Case: SOT23
- Case material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)







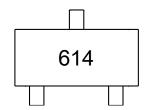
### Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT614QTA	Automotive	614	7	8	3,000
FMMT614QTC	Automotive	614	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



614 = Product Type Marking Code



## **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	120	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	V <sub>EBO</sub>	10	V
Continuous Collector Current	Ic	500	mA
Peak Pulse Current	I <sub>CM</sub>	2	А

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	$P_D$	500	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 7)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C

# ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	2,000	V	2
Electrostatic Discharge - Machine Model	ESD MM	200	V	В

Notes:

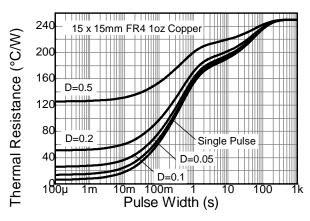
<sup>6.</sup> For a device mounted on 15mm X 15mm 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions while operating in a steady-state.

<sup>7.</sup> Thermal resistance from junction to solder-point (at the end of the collector lead).

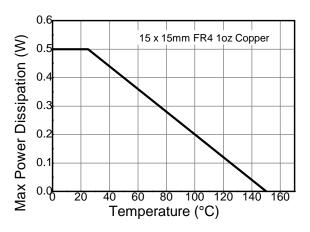
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



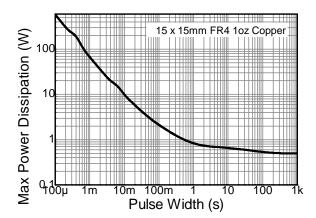
# **Thermal Characteristics and Derating Information**



**Transient Thermal Impedance** 



**Derating Curve** 



**Pulse Power Dissipation** 



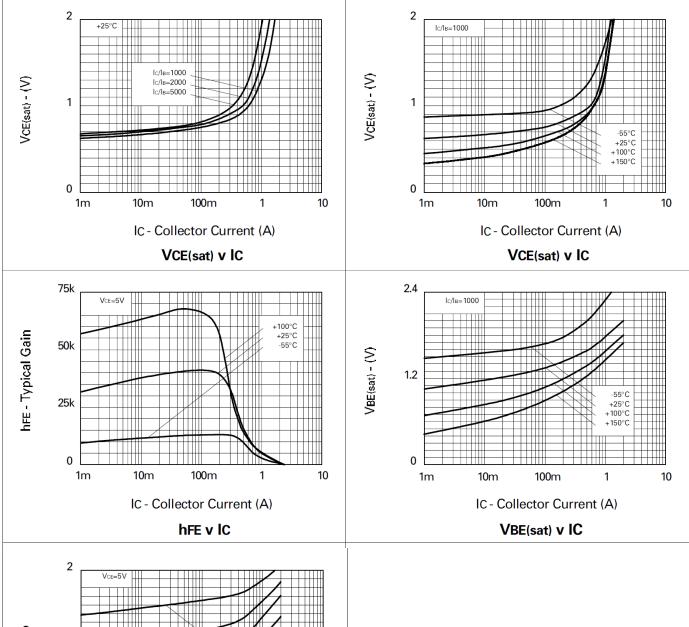
# **Electrical Characteristics** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	120	300	_	V	I <sub>C</sub> = 10μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	100	130	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	10	14	_	V	$I_E = 10\mu A$
Collector Cutoff Current	I <sub>CBO</sub>	_	0.02	10	nA	V <sub>CB</sub> = 100V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	100	nA	V <sub>EB</sub> = 8V
Collector Emitter Cutoff Current	I <sub>CES</sub>	_	_	10	μΑ	V <sub>CE</sub> = 100V
Static Forward Current Transfer Ratio (Note 9)	h <sub>FE</sub>	15k 5k			_	$I_C = 100$ mA, $V_{CE} = 5$ V $I_C = 500$ mA, $V_{CE} = 5$ V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	0.9 0.78	1.0 0.9	V V	I <sub>C</sub> = 500mA, I <sub>B</sub> = 5mA I <sub>C</sub> = 100mA, I <sub>B</sub> = 0.1mA
Base-Emitter Turn-On Voltage(Note 9)	V <sub>BE(on)</sub>	_	1.5	1.8	V	I <sub>C</sub> = 500mA, V <sub>CE</sub> = 5V
Base-Emitter Saturation Voltage(Note 9)	V <sub>BE(sat)</sub>	_	1.7	1.9	V	I <sub>C</sub> = 500mA, I <sub>B</sub> = 5mA
Output Capacitance	C <sub>obo</sub>	_	6	_	pF	V <sub>CB</sub> = 10V, f = 100mHz
Switching Times	t <sub>on</sub>		0.7		μs	$I_C = 100\mu A, I_B = 0.1 mA,$
Switching Times	t <sub>off</sub>	_	2.5	_	μs	V <sub>S</sub> = 10V

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



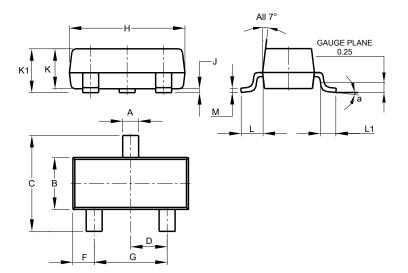
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





## **Package Outline Dimensions**

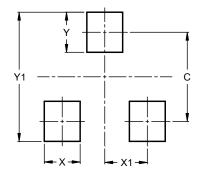
Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
M	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	2.0		
X	0.8		
X1	1.35		
Y	0.9		
Y1	2.9		

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance Note: distances between device Terminals and PCB tracking.



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